## NSN 5961-01-040-6426

**Fiig:** A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-040-6426 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.687 inches and 0.693 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 50.00 amperes forward current, total rms megahertz **Test Data Document:** 05869-3001-752 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No